17OCT2013 Rev.A

PUSH-PUSH Micro SIM CONNECTOR

1.Introduction

1.1 Objective

Testing was performed on the PUSH-PUSH Micro SIM CONNECTOR to determine

if it meets the requirement of product specification, 108-78956

1.2 Scope

This report covers the electrical, mechanical and environment performance requirements of the PUSH-PUSH Micro SIM CONNECTOR.

The qualification testing was performed between 03JUN2013 and 12JUL2013.

The following documents form a part of this specification to the extent specified herein. In the event of conflict between the requirements of this specification and the product drawing, the product drawing shall take precedence. In the event of conflict between the requirements of this specification and the referenced documents, this specification shall take precedence.

1.3 Conclusion

The PUSH-PUSH Micro SIM CONNECTOR meets the electorical, mechanical and environmental performance requirements of product specification, 108-78956

1.4 Product description

The PUSH-PUSH Micro SIM CONNECTOR is designed to make a connection between a Subscriber Identity Module (SIM) and printed circuit board.

1.5 Test samples

Samples were taken randomly from mass production samples. The follwing samples were used.

Part number	Description
2229333-2	PUSH-PUSH Micro SIM CONNECTOR SMT type
TB-1710	Test card

Fig.1

* Trademark



2. Test contents

Para.	Test items	Requirements	Judgment
2.1	Examination of product	Visual inspection No physical damage	Acceptable
		Electrical requirements	
2.2	Contact resistance (low level)	 Initial contact resistance: 150mΩ Max. Max contact resistance after group testing: 150mΩ Max. Contact resistance includes also the bulk resistance due to terminal After any environmental test for every contact Detection switch: 500mΩMax. Mate connector with dry circuit (20mV, 100mA Max.) 4-wire measurement required Measure resistance with minimum thickness memory card (or PWB) (IEC 60512-2-1) 	Acceptable
2.3	Insulation resistance	·1000MΩ Min. ·Unmated connector with 500 VDC between adjacent contact for 1 minute (IEC 60512-3-1)	Acceptable
2.4	Dielectric strength	No voltage breakdown Unmated connector with 500 VAC between adjacent contact for 1 minute (IEC 60512-3-1)	Acceptable
2.5	Temperature rise	·30°C Max. under loaded rating current (0.5A) ·Contacts series-,apply test current of loaded rating current of the circuit ·Measure the temperature rising by probing on soldered areas of contacts ·After the temperature becomes stabilized deduct ambient temperature from the measured	Acceptable

Fig. 2 (CONT.)

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Para.	Test items	Requirements	Judgment
		Mechanical requirements	
2.6	Durability (1500 cycle)	Contact resistance: 150mΩ Max. No mechanical damage for connector as well as Micro SIM cards Eject length: 2.8mm REF. Mating contacts at 4-10 cycles/minute, including pause between mate/unmate to 1500 cycles After every 10 (Max.) cycles blow with dry air	Acceptable
2.7	Wrongly insertion test card upside down	·30N Min. ·No mechanical damage ·The card cannot be stuck in the reader	Acceptable
		Environmental requirements	•
2.8	Dry cold (steady state)	No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) -40°C for 96hours; recovery period 1-2hours under ambient atmospheric conditions	Acceptable
2.9	Dry heat (steady state)	 (IEC60068-2-1Ab) No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) +85°C for 96 hours; recovery period 1-2hours under ambient atmospheric conditions (IEC60068-2-2Bb) 	Acceptable
2.10	Thermal shock (change of temperature)	 No mechanical damage No change to performance Contact resistance: 150mΩ Max.(Data) 25 cycle at T_a = -55 °C for 0.5 hours; then change of temp=25°C Max. 5 minute; then T_b=+85°C for 0.5 hours; then cool to ambient Recovery: 2 hours at ambient atmosphere (IEC60068-2-14 Test Na) 	Acceptable
2.11	Humidity - temperature cycling	 No change to performance Contact resistance:150 mΩ Max. Insulation Resistance should be measured Measure the resistance without opening the mating after test Temp 25-65°C, RH 50-80% for 10 cycles Cold shock -10°C performed (EIA-364-31)	Acceptable

Fig. 2 (CONT.)

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Para.	Test items	Requirements	Judgment
2.12	SO ₂ gas	 No mechanical damage No change to performance Contact resistance: 150mΩ Max. (Data) 10±3ppm, Damp 75% at 40±2°C, 48hours 	Acceptable
2.13	Vibration (random)	 Discontinuity during testing 1 µs with all contacts in series No mechanical damage No change to performance Contact resistance: 150mΩ Max. Frequency:10 - 100 Hz; 3 m²/s³ (0.0132 g²/Hz);100 - 500 Hz; -3dB/Oct. for: 3 x 60 minute (X- Y- and Z-axis) (IEC60068-2-64Fh) 	Acceptable
2.14	Shock (specified pulse)	 Discontinuity during testing 1 µs with all contacts in series No mechanical damage No change to performance Contact resistance: 150mΩ Max. Pulse shape=half sine Peak acceleration=50G Duration of pulse=11ms Apply 3 shocks in each direction along the 3 mutually perpendicular axes (18 shocks) (IEC60068-2-27Ea) 	Acceptable

Fig. 2 (CONT.)

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3. Product qualification test sequence

	Test Eveninstien					Test 0	Group			
Para.	Test Examination	1	2	3	4	5	6	7	8	9
3.5.1	Examination of product	1,7	1,5	1,5	1,5	1,5	1,5	1,6	1,3	1,3
3.5.2	Contact resistance (low level)		2,4	2,4	2,4	2,4	2,4	2,5		
3.5.3	Insulation resistance	2,5								
3.5.4	Dielectric strength	3,6								
3.5.5	Temperature rise								2	
3.5.6	Durability						3			
3.5.7	Wrongly Insertion test card upside down									2
3.5.8	Dry cold (steady state)		3							
3.5.9	Dry heat (steady state)			3						
3.5.10	Thermal shock (change of temperature)				3					
3.5.11	Humidity-temperature cycling	4								
3.5.12	SO₂ gas					3				
3.5.13	Vibration (random)							3		
3.5.14	Shock (specified pulse)							4		

⁽a) Numbers indicate sequence in which the tests are performed.

Fig. 3

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4. Test results

Test item	Unit		Result	Requirements	Judge
Took nom	010	N	Max. Min. Ave. Sig.		-ment
			Test group 1		
Examination of product	-	5	No abnormalities	No abnormalities	Accept -able
Insulation resistance	Ω	5	35700000MΩ Min.	1000MΩ Min.	Accept -able
Dielectric strength	-	5	No abnormalities	No abnormalities	Accept -able
Insulation resistance after Humidity-temperature cycling	Ω	5	194000MΩ Min.	1000MΩ Min.	Accept -able
Dielectric strength after Humidity-temperature cycling	ı	5	No abnormalities	No abnormalities	Accept -able
Examination of product after Humidity-temperature cycling	-	5	No abnormalities	No abnormalities	Accept -able

Test item	Test item				Resu	lt		Requirements	Judge
			N	Max.	Min.	Ave.	Sig.	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	-ment
				Tes	st group	2			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	11.0	3.7	7.1	2.33	150mΩ Max.(initial) Detection switch :500mΩMax.	Accept -able
Contact resistance	Detection switch	11152	5	151.1	127.3	139.1	10.56		
Contact resistance	Contact	mΩ	30	11.1	4.0	7.3	2.21	150mΩ Max.(final) Detection switch	Accept
after dry cold	Detection switch	11152	5	161.3	130.3	145.6	12.55	:500mΩMax.	-able
Examination of product after dry cold		-	5	No abr	normaliti	es		No abnormalities	Accept -able

Group 1,2 (End)

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Test item	Test item				Resu	lt		Requirements	Judge
1000 110111		Unit	Ν	Max.	Min.	Ave.	Sig.	rtoquiromonio	-ment
				Tes	st group	3			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	9.4	3.0	6.2	2.08	150mΩ Max.(initial) Detection switch	Accept -able
Contact resistance	Detection switch	11152	5	171.4	147.5	160.8	9.34	:500mΩMax.	
Contact resistance	Contact	mΩ	30	10.2	2.7	6.4	2.22	150mΩ Max.(final) Detection switch	Accept
after dry heat	Detection switch	111152	5	176.6	139.6	157.1	15.26	:500mΩMax.	-able
Examination of product after dry heat			5	No abr	normaliti	es		No abnormalities	Accept -able

Test item	Test item				Resu	lt		Requirements	Judge
		Unit	Ν	Max.	Min.	Ave.	Sig.		-ment
				Tes	st group	4			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	9.4	3.0	6.2	2.04	150mΩ Max.(initial) Detection switch :500mΩMax.	Accept -able
Contact resistance	Detection switch	11152	5	162.9	156.3	158.9	2.76		
Contact resistance	Contact	mΩ	30	9.7	2.9	6.3	2.12	150mΩ Max.(final) Detection switch	Accept
after thermal shock	Detection switch	11132	5	186.1	140.0	163.0	20.24	:500mΩMax.	-able
Examination of product after thermal shock		-	5	No abr	normaliti	es		No abnormalities	Accept -able

Group 3,4 (End)

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Test item	Test item				Resu	lt		Requirements	Judge
1000 110111		Unit	Ν	Max.	Min.	Ave.	Sig.	rtoquilomonio	-ment
				Tes	st group	5			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	9.8	3.2	6.2	1.99	150mΩ Max.(initial) Detection switch	Accept -able
Contact resistance	Detection switch	11152	5	162.3	137.2	146.2	10.26	:500mΩMax.	
Contact resistance	Contact	mΩ	30	13.5	3.3	7.1	2.94	150mΩ Max.(final) Detection switch	Accept
after SO ₂ gas	Detection switch	111152	5	178.7	153.7	168.1	10.04	:500mΩMax.	-able
Examination of product SO ₂ gas			5	No abr	normaliti	es		No abnormalities	Accept -able

Test item		Unit	N	Max.	Resu Min.	lt Ave.	Sig.	Requirements	Judge -ment
					st group			1	
Examination of product			5	No abnormalities				No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	10.8	3.2	7.3	2.28	150mΩ Max.(initial) Detection switch	Accept
Contact resistance	Detection switch	11152	5	148.3	138.3	143.5	4.25	:500mΩMax.	-able
Durability		-	5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	9.5	3.3	6.7	1.79	150mΩ Max.(final) Detection switch	Accept
after durability	Detection switch	11152	5	146.8	132.8	138.5	5.94	:500mΩMax.	-able
Examination of prod after durability	-	5	No abnormalities				No abnormalities	Accept -able	

Group 5,6 (End)

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Test item		Unit			Resu	lt		Requirements	Judge
			N	Max.	Min.	Ave.	Sig.		-ment
				Tes	st group	7			
Examination of product			5	No abr	normaliti	es		No abnormalities	Accept -able
Contact resistance	Contact	mΩ	30	11.9	4.0	7.3	2.27	150mΩ Max.(initial) Detection switch	Accept
Contact resistance	Detection switch	11152	5	150.1	137.6	144.3	4.91	:500mΩMax.	-able
Vibration (random)		-	5	No abr	normaliti	es		1µs Max.	Accept -able
Shock (specified pul	se)	-	5	No abr	normaliti	es		1µs Max.	Accept -able
Contact resistance after vibration and	Contact	mΟ	30	11.3	3.7	7.8	2.33	150mΩ Max.(final) Detection switch	Accept
shock	Detection switch	11152	5	164.7	146.6	154.5	6.98	:500mΩMax.	-able
Examination of production and shape		-	5	No abr	normaliti	es		No abnormalities	Accept -able

Test item	Unit	Result					Requirements	Judge				
		Ν	Max.	Min.	Ave.	Sig.		-ment				
Test group 8												
Examination of product	-	5	No abnormalities				No abnormalities	Accept -able				
Temperature rise	°C	5	1.35	1.25	1.27	0.045	30°C Max.	Accept -able				
Examination of product after temperature rise	-	5	No abnormalities				No abnormalities	Accept -able				

Group 7,8 (End)

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Test item	Unit	N	Result	Requirements	Judge -ment					
Test group 9										
Examination of product	1	5	No abnormalities	No abnormalities	Accept -able					
Wrongly insertion test card upside down	1	5	No mechanical damage at 30N (broken force : 72.1N Min)	30N Min.	Accept -able					
Examination of product	1	5	No abnormalities	No abnormalities	Accept -able					

Group 9 (End)

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